TOSHIBA CCD Linear Image Sensor CCD (Charge Coupled Device)

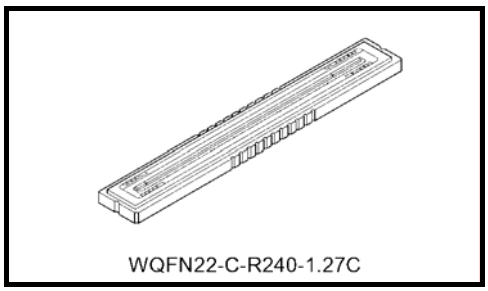
TENTATIVE

TCD2565BFG

The TCD2565BFG is a high sensitive and low dark current 5400 pixels × 4 line CCD color image sensor. The sensor is designed for color scanner.

The device contains a row of 5400 pixels × 4 line photodiodes which provide a 24 lines/mm across a A4 size paper.

The device is operated by 5.0 V pulse and 10 V power supply.



Weight: 2.0 g (typ.)

Features

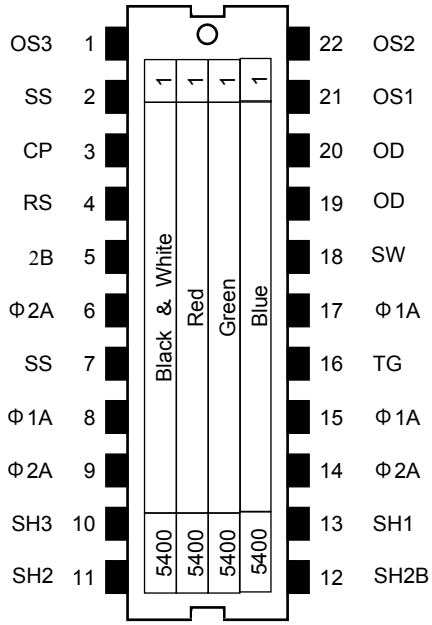
- Number of image sensing pixels : 21600 pixels (5400 pixels × 4 line)
- Image sensing pixels size : 5.25 μm by 5.25 μm on 5.25 μm center
- Photo sensing region : High sensitive pn photodiode
- Clock : 2-phase (5 V)
- Distance between photodiode array
  :Pixel B to pixel G: 10.5 μm (2 lines)
  Pixel G to pixel R: 10.5 μm (2 lines)
  Pixel R to pixel B/W: 31.5 μm (6 lines)
- Internal circuit : Clamp circuit
- Package : 22 pin CLCC
- Color filter : Red, Green, Blue

Maximum Ratings (Note 1)

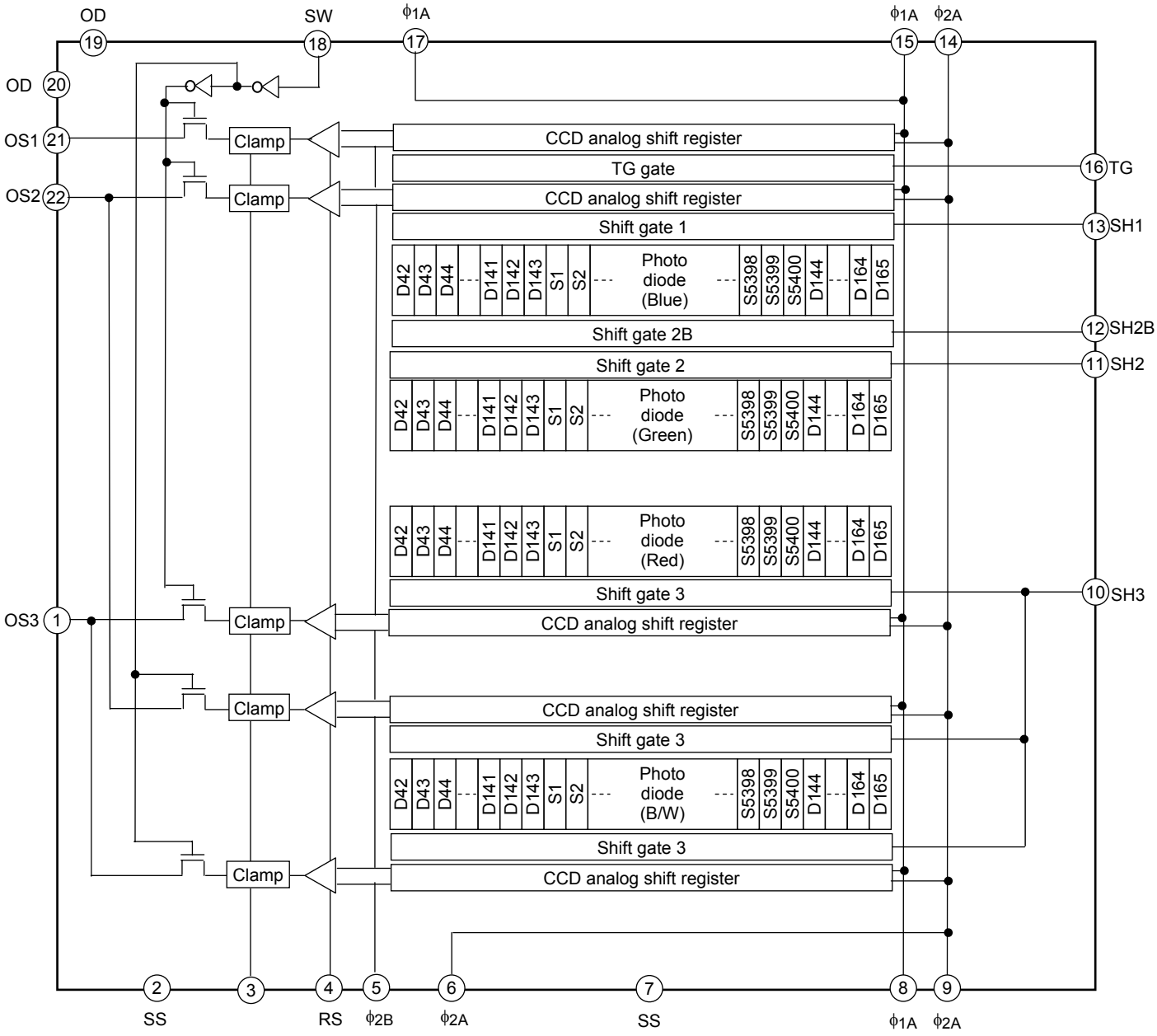
Characteristics	Symbol	Rating	Unit
Clock pulse voltage	$V_{\phi A}$	−0.3~8	V
Clock pulse voltage	$V_{\phi B}$		
Shift pulse voltage	V_{SH}		
Reset pulse voltage	V_{RS}		
Clamp pulse voltage	V_{CP}		
TG pulse voltage	V_{TG}		
SW pulse voltage	V_{SW}		
Power supply voltage	V_{OD}	−0.3~13.5	V
Operating temperature	t_{opr}	0~60	°C
Storage temperature	t_{stg}	−25~85	°C

Note 1: All voltages are with respect to SS pins (ground)

PIN CONNECTIONS (top view)



Circuit Diagram



Pin Names

OS 1	Output Signal 1 (Blue)	ϕ_{1A}	Transfer clock (phase 1)
OS 2	Output signal 2 (Green、B/W（ODD）)	ϕ_{2A}	Transfer clock (phase 2)
OS 3	Output signal 3 (Red、B/W（EVEN）)	SH1	Shift gate 1
SS	Ground	SH2	Shift gate 2
OD	Power supply	SH2B	Shift gate 2B
RS	Reset gate	SH3	Shift gate 3
CP	Clamp gate	ϕ_{2B}	Last stage transfer clock（phase 2）
TG	TG gate	SW	Switch Gate for Color or B/W

Optical/Electrical Characteristics1（Color mode）
(Ta = 25°C, V_{OD} = 10 V, V_{SW} = 5 V, V_{ϕ} = V_{SH} = V_{RS} = V_{CP}= V_{TG}= 5 V (pulse), f_{ϕ} = 1 MHz, load resistance = 100 kΩ, t_{INT} (integration time) = 10 ms, light source = A light source + CM500S filter (t = 1.0 mm))

Characteristics		Symbol	Min	Typ.	Max	Unit	Note
Sensitivity	Red	R (R)	7.1	10.2	13.3	V/lx·s	(Note 2)
	Green	R (G)	6.4	9.2	12.0		
	Blue	R (B)	2.8	4.0	5.2		
Photo response non uniformity		PRNU (1)	—	10	20	%	(Note 3)
		PRNU (3)	—	3	12	mV	(Note 4)
Saturation output voltage		V_{SAT}	1.5	2.0	—	V	(Note 5)
Saturation exposure		SE	0.11	1.19	—	lx·s	(Note 6)
Dark signal voltage		V_{DRK}	—	1	6	mV	(Note 7)
Dark signal non uniformity		DSNU	—	6	12	mV	(Note 8)
Dc power dissipation		P_D	—	450	550	mW	—
Total transfer efficiency		TTE	92	98	—	%	—
Output impedance		Z_O	—	0.2	0.5	kΩ	—
Dc signal output voltage		V_{OS}	4.0	5.0	6.0	V	(Note 9)
Random noise		$N_{D\sigma}$	—	0.8	—	mV	(Note 10)

Optical/Electrical Characteristics2（B/W mode）
(Ta = 25°C, V_{OD} = 10 V, V_{SW} = 0 V, V_{ϕ} = V_{SH} = V_{RS} = V_{CP}= V_{TG}= 5 V (pulse), f_{ϕ} = 1 MHz, load resistance = 100 kΩ, t_{INT} (integration time) = 10 ms, light source = A light source + CM500S filter (t = 1.0 mm))

Characteristics	Symbol	Min	Typ.	Max	Unit	Note
Sensitivity	R (B/W)	11.7	14.7	17.6	V/lx·s	(Note 2)
Photo response non uniformity	PRNU (1)	—	10	20	%	(Note 3)
	PRNU (3)	—	3	12	mV	(Note 4)
Saturation output voltage	V_{SAT}	1.5	2.0	—	V	(Note 5)
Saturation exposure	SE	0.08	0.13	—	lx·s	(Note 6)
Dark signal voltage	V_{DRK}	—	1	6	mV	(Note 7)
Dark signal non uniformity	DSNU	—	6	12	mV	(Note 8)
Dc power dissipation	P_D	—	430	550	mW	—
Total transfer efficiency	TTE	92	98	—	%	—
Output impedance	Z_O	—	0.2	0.5	kΩ	—
Dc signal output voltage	V_{OS}	4.0	5.0	6.0	V	(Note 9)
Random noise	$N_{D\sigma}$	—	0.6	—	mV	(Note 10)

Note 2:Sensitivity is defined for each color of signal outputs average when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

Note 3:PRNU (1) is defined for each color on a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

$$\text{PRNU (1)} = \frac{\Delta\chi}{\bar{\chi}} \times 100\ (\%)$$

$\bar{\chi}$: Average of total signal outputs
$\Delta\chi$: The maximum deviation from $\bar{\chi}$.

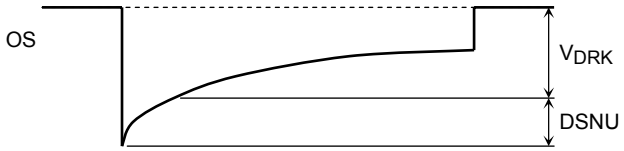
Note 4:PRNU (3) is defined as maximum voltage with next pixel, where measured 5% of SE (typ.).

Note 5:V_{SAT} is defined as minimum saturation output voltage of all effective pixels.

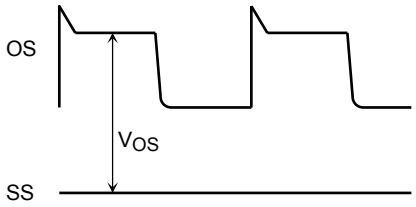
Note 6:Definition of SE: $\text{SE} = \frac{V_{SAT}}{RG}$

Note 7:V_{DRK} is defined as average dark signal voltage of all effective pixels.

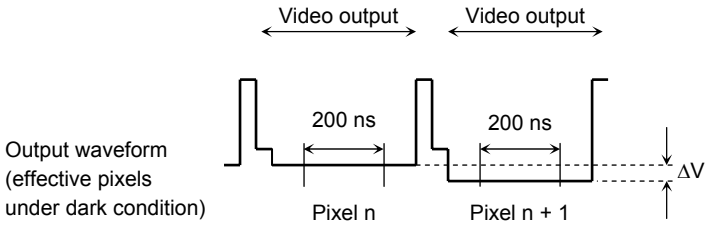
Note 8:DSNU is defined by the difference between average value (V_{DRK}) and the maximum value of the dark voltage.



Note 9:DC signal output voltage is defined as follows:



Note 10:Random noise is defined as the standard deviation (sigma) of the output level difference between two adjacent effective pixels under no illumination (i.e. dark condition) calculated by the following procedure.



1) Two adjacent pixels (pixel n and n + 1) in one reading are fixed as measurement points.
2) Each of the output levels at video output periods averaged over 200 nanosecond period to get Vn and Vn + 1.
3) Vn + 1 is subtracted from Vn to get ΔV.
   ΔV = Vn − Vn + 1
4) The standard deviation of ΔV is calculated after procedure 2) and 3) are repeated 30 times (30 readings).

$$\Delta V = \frac{1}{30}\sum_{i=1}^{30}|\Delta Vi| \qquad \sigma = \sqrt{\frac{1}{30}\sum_{i=1}^{30}\left(|\Delta Vi| - \overline{\Delta V}\right)^2}$$

5) Procedure 2), 3) and 4) are repeated 10 times to get 10 sigma values.

$$\overline{\sigma} = \frac{1}{10}\sum_{j=1}^{10}\sigma j$$

6) $\overline{\sigma}$ value calculated using the above procedure is observed $\sqrt{2}$ times larger than that measured relative to the ground level. So we specify the random noise as follows.

$$\text{Random noise} = \frac{1}{\sqrt{2}}\overline{\sigma}$$

Operating Condition (Ta = 25°C)

Characteristics		Symbol	Min	Typ.	Max	Unit
Clock pulse voltage	"H" level	$V_{\phi 1A}$	4.75	5	5.5	V
	"L" level	$V_{\phi 2A}$	0	—	0.25	
Final stage clock pulse voltage	"H" level	$V_{\phi 2B}$	4.75	5	5.5	V
	"L" level		0	—	0.25	
Shift pulse voltage	"H" level	V_{SH}	4.75	5	5.5	V
	"L" level		0	—	0.25	
Reset pulse voltage	"H" level	V_{RS}	4.75	5	5.5	V
	"L" level		0	—	0.25	
Clamp pulse voltage	"H" level	V_{CP}	4.75	5	5.5	V
	"L" level		0	—	0.25	
TG pulse voltage	"H" level	V_{TG}	4.75	5	5.5	V
	"L" level		0	—	0.25	
SW pulse voltage	"H" level	V_{SW}	4.75	5	5.5	V
	"L" level		0	—	0.25	
Power supply voltage		V_{OD}	9.5	10	10.5	

Clock Characteristics (Ta = 25°C)

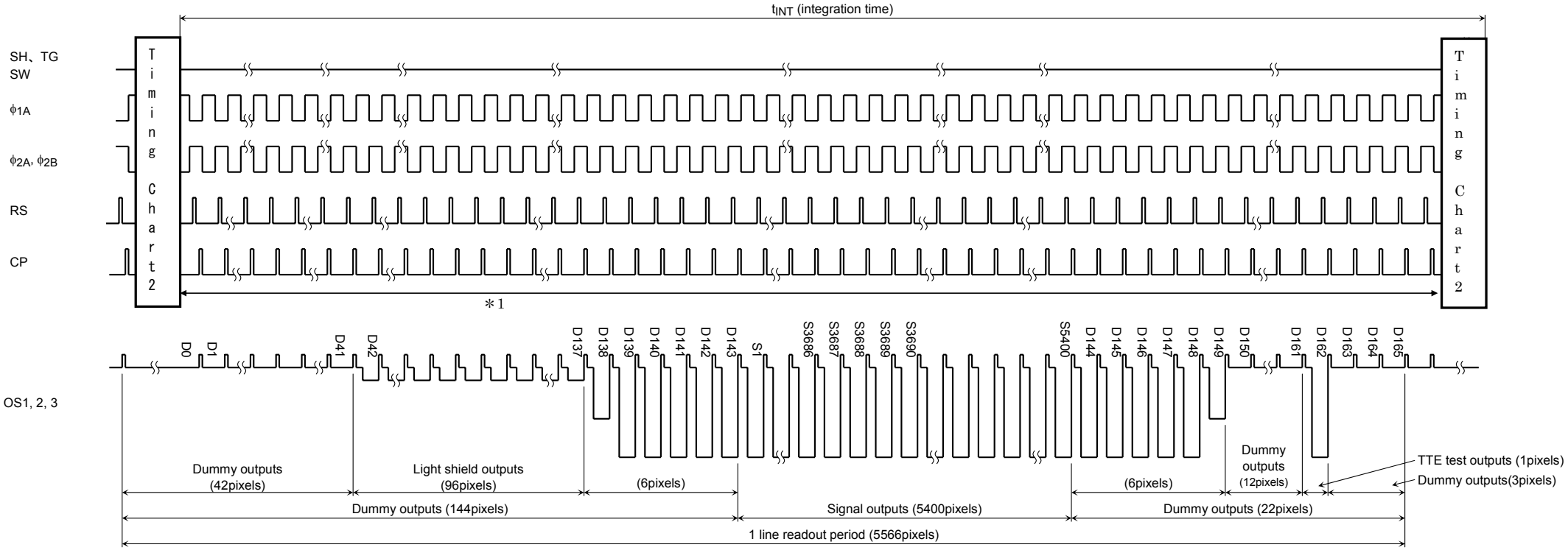
Characteristics	Symbol	Min	Typ.	Max	Unit
Clock pulse frequency	f_{ϕ}	0.5	1	35	MHz
Reset pulse frequency	f_{RS}	0.5	1	35	MHz
Clamp pulse frequency	f_{CP}	0.5	1	35	MHz
Clock capacitance (Note 11)	$C_{\phi A}$	—	80	—	pF
Final stage clock capacitance	$C_{\phi B}$	—	10	—	pF
Shift gate capacitance	C_{SH}	—	20	—	pF
Reset gate capacitance	C_{RS}	—	10	—	pF
Clamp gate capacitance	C_{CP}	—	10	—	pF
TG gate capacitance	C_{TG}	—	10	—	pF
SW gate capacitance	C_{SW}	—	10	—	pF

Note 11: V_{OD} = 10 V

Select mode of B/W and Color

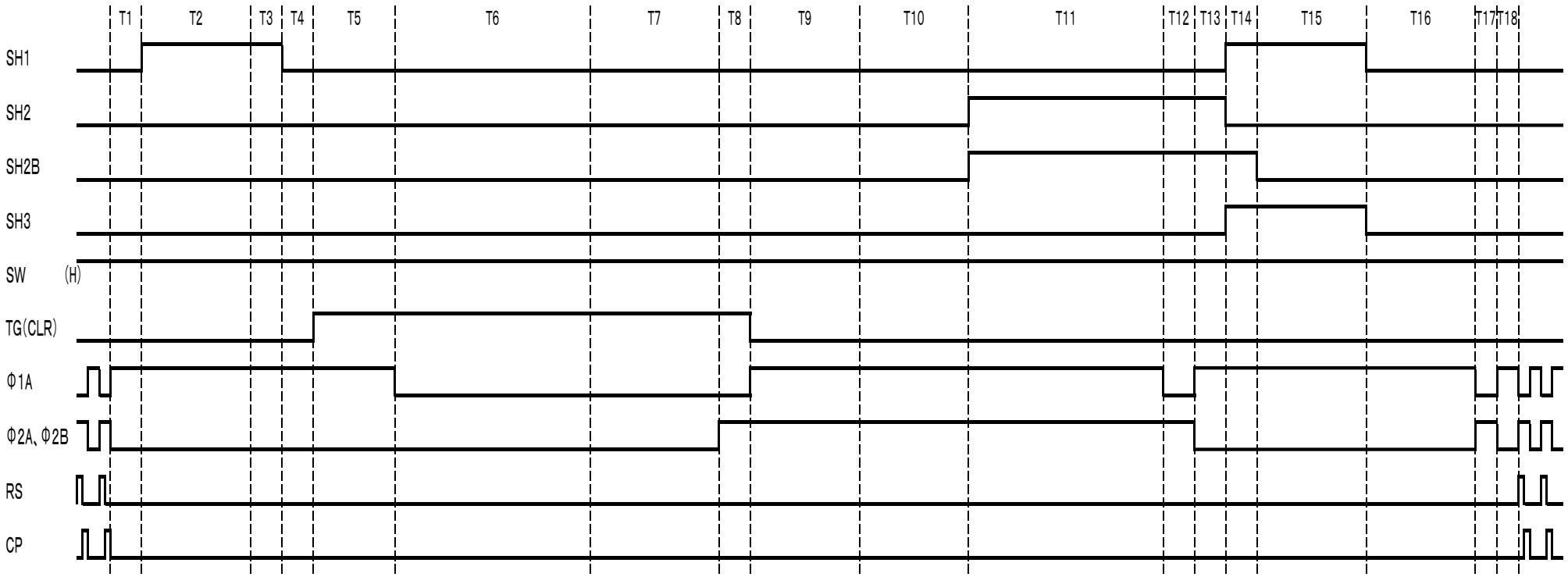
	SW gate condition
Color	"H"
B/W	"L"

Timing Chart 1: (color mode)

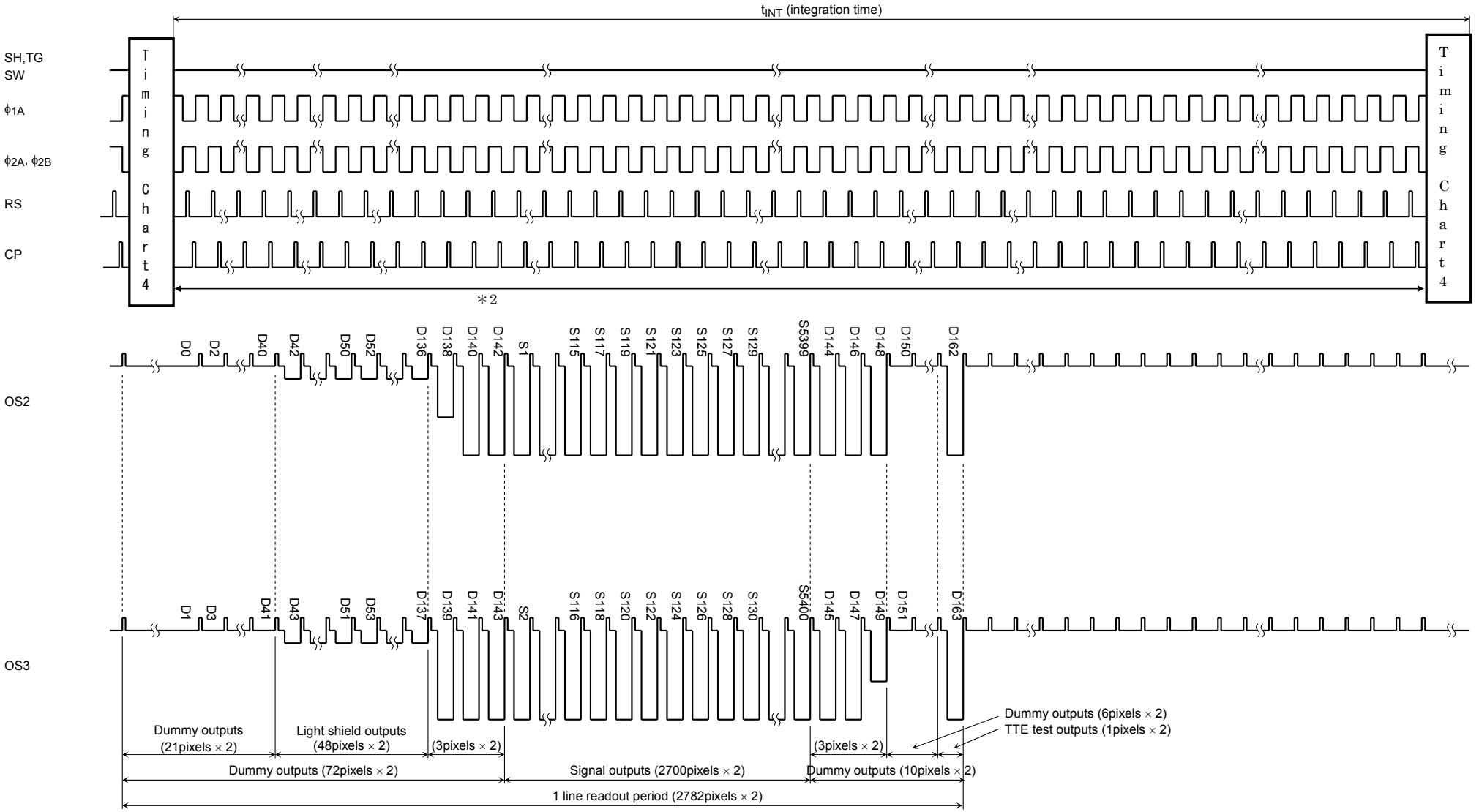


＊1：Hold the SH and TG pins at low and the SW pins at high during this period.

Timing Chart 2 (Color mode Vertical transfer)

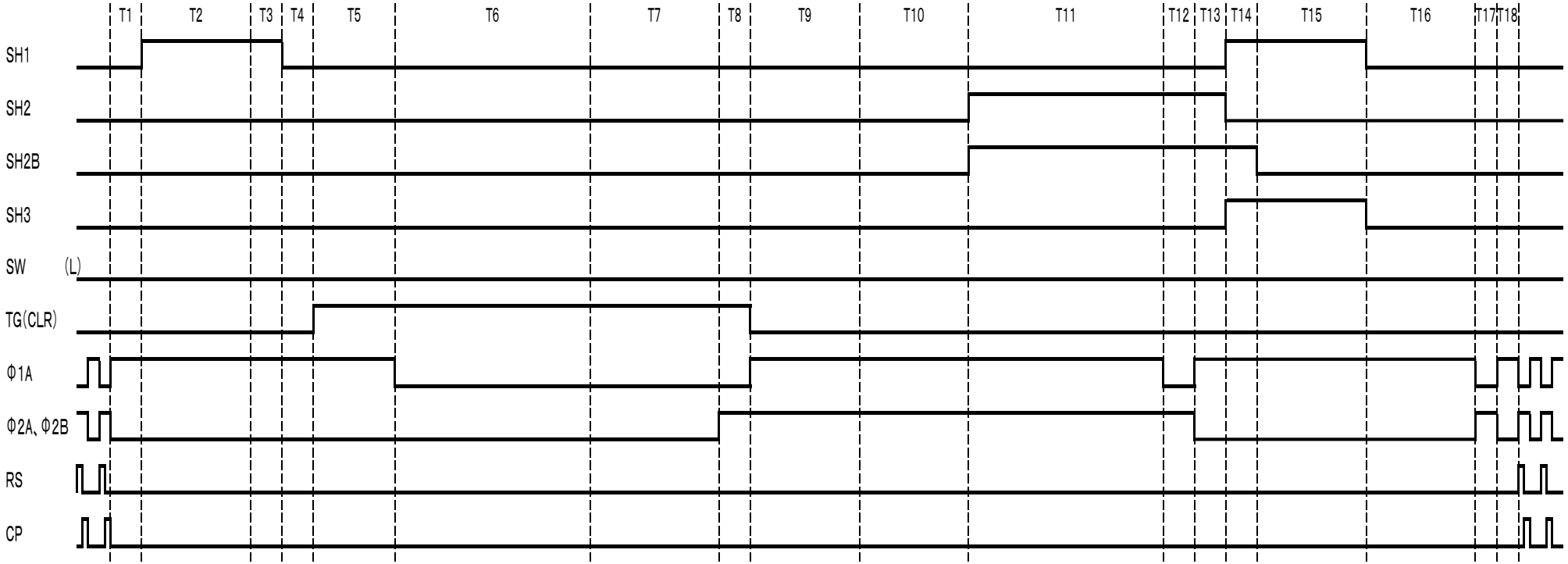


Timing Chart 3: (B/W mode)

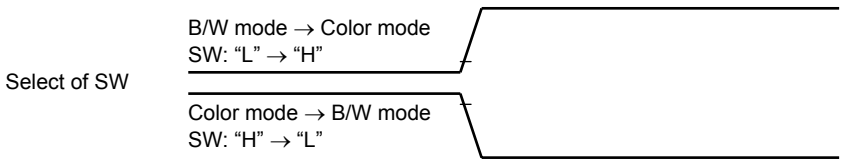


＊2 : Hold the SH and TG and SW pins at low during this period.

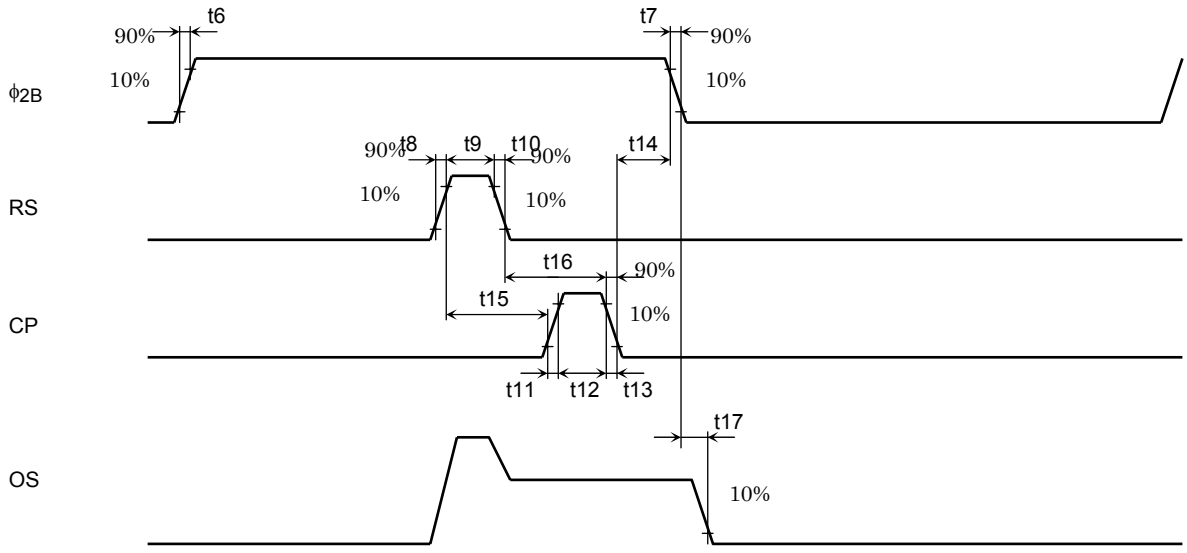
Timing Chart 4: (B/W mode Vertical transfer)

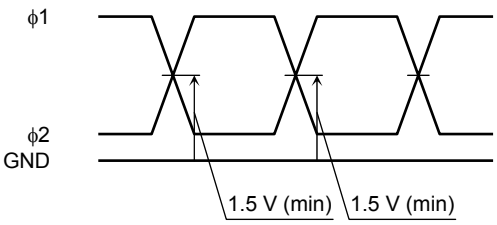


Timing Requirements 1



Note 12: Please scan the dummy more than 4 lines after the change of the mode.





Characteristics	Symbol	Min	Typ. (Note 13)	Max	Unit
ϕ1, ϕ2 Pulse rise time, fall time	t6, t7	0	50	—	ns
RS pulse rise time, fall time	t8, t10	0	20	—	ns
RS pulse width	t9	6	100	—	ns
CP pulse rise time, fall time	t11, t13	0	20	—	ns
CP pulse width	t12	6	200	—	ns
Pulse timing of ϕ2B and CP	t14	0	40	—	ns
Pulse timing of RS and CP	t15	0	0	—	ns
	t16	6	100	—	ns
Video data delay time (Note 14)	t17	—	7	—	ns

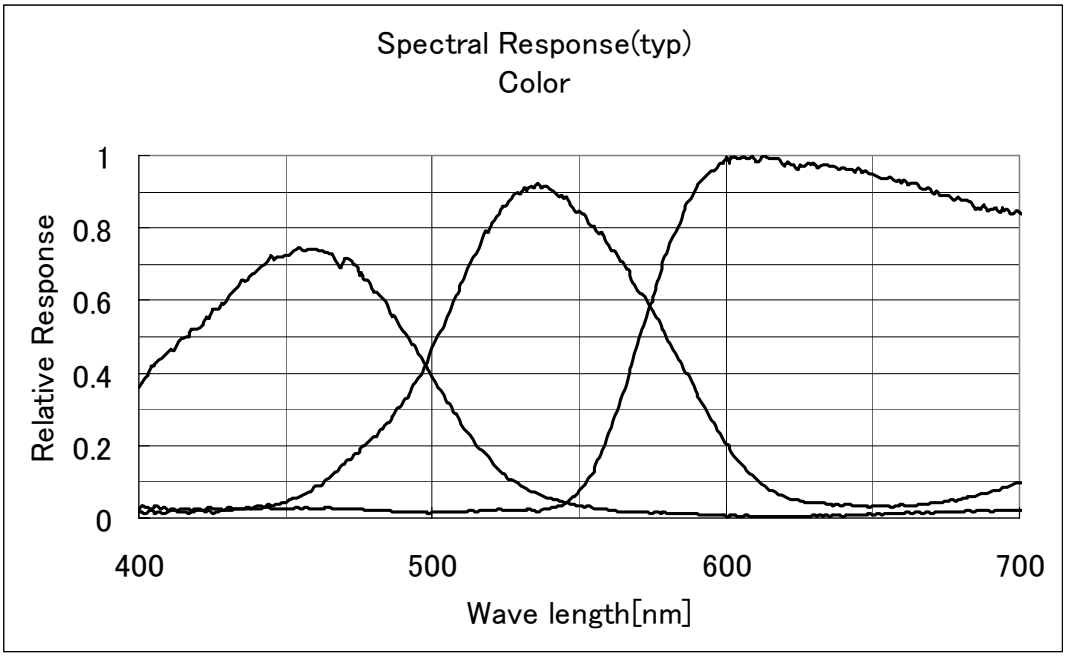
Note13:Measured with fRS=1MHz

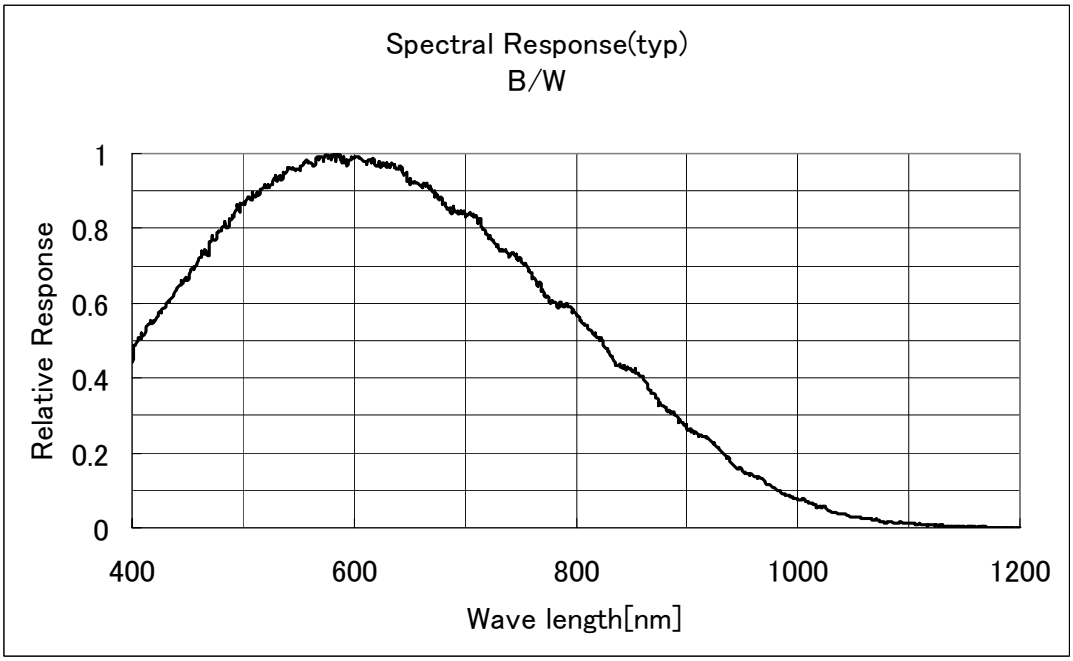
Note14:Load resistance is 100kΩ

Timing Requirements 2

Timing address	Min	Typ	Max	Unit
1	100	200	—	ns
2	500	1000	—	
3	100	200	—	
4	100	200	—	
5	400	800	—	
6	1000	2000	—	
7	600	1200	—	
8	100	200	—	
9	500	1000	—	
10	500	1000	—	
11	1000	2000	—	
12	100	200	—	
13	100	200	—	
14	100	200	—	
15	500	1000	—	
16	500	1000	—	
17	50	100	—	
18	50	100	—	
Vertical Transfer Time	6.3	12.6	—	us

Spectral Response





Caution

1. Electrostatic Breakdown

Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

CCD Image Sensor is protected against static electricity, but inferior puncture mode device due to static electricity is sometimes detected. In handing the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.
b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.
c. Ground the tools such as soldering iron, radio cutting pliers of or pincer.
   It is not necessarily required to execute all precaution items for static electricity.
   It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.
d. Ionized air is recommended for discharge when handling CCD image sensors.

2. Incident Light

CCD sensor is sensitive to infrared light. Note that infrared light component degrades resolution and PRNU of CCD sensor.

3. Cloudiness of Glass Inside

CCD surface mount products may have a haze on the inside of glass, so be careful about following. Even if the haze arises inside of glass, when it is not on the pixel area, there is no problem in quality.

・Before the aluminum bag is opened, please keep the products in the environment below 30℃90%RH. And after the aluminum bag is opened, please keep the products in the environment below 30℃60%RH .

・ Please mount the products within 12month from sealed date and within 6 month from opening the aluminum bag. (Sealed date is printed on aluminum bag.)

4. Ultrasonic Cleaning

Ultrasonic cleaning should not be used with such hermetically-sealed ceramic package as CCD because the bonding wires can become disconnected due to resonance during the cleaning process.

5. Mounting

In the case of solder mounting, the devices should be mounted with the window glass protective tape in order to avoid dust or dirt included in reflow machine.

6. Window Glass Protective Tape

The window glass protective tape is manufactured from materials in which static charges tend to build up. When removing the tape from CCD sensor after solder mounting, install an ionizer to prevent the tape from being charged with static electricity.

When the tape is removed, adhesives will remain in the glass surface. Since these adhesives appear as black or white flaws on the image, please wipe the window glass surface with the cloth into which the organic solvent was infiltrated. Then please attach CCD to a product.

Do not reuse the tape.

7. Soldering Temperature Profile for Pb free

Good temperature profile for each soldering method is as follows. In addition, in case of the repair work accompanied by IC removal, since the degree of parallel may be spoiled with the left solder, please do not carry out and in case of the repair work not accompanied by IC removal, carry out with a soldering iron or , in reflow, only one time.

a. Using a soldering iron
   Complete soldering within ten seconds for lead temperatures of up to 260°C, or within three seconds for lead temperatures of up to 350℃.
b. Using long infrared rays reflow / hot air reflow
   Please do reflow at the condition that the package surface (electrode) temperature is on the solder maker's recommendation profile. And that reflow profile is within below condition 1 to 3.

1. Peak temperature: 250℃ or less.
2. Time to keep high temperature : 220～250℃, 30～40sec.
3. Pre. heat : 150～190℃, 60～120sec

8. Window Glass

The dust and stain on the glass window of the package degrade optical performance of CCD sensor.

Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N2. Care should be taken to avoid mechanical or thermal shock because the glass window is easily to damage.

9. Cleaning Method of the Window Glass Surface

Wiping Cloth

a. Use soft cloth with a fine mesh.
b. The wiping cloth must not cause dust from itself.
c. Use a clean wiping cloth necessarily.

Recommended wiping cloth is as follow;

- MK cloth (Toray Industries)

Cleaner

Recommended cleaning liquid of window glass are as follow;

- EE-3310 (Olympus)

When using solvents, such as alcohol, unavoidably, it is cautious of the next.

a. A clean thing with quick-drying.
b. After liquid dries, there needs to be no residual substance.
c. A thing safe for a human body.

And, please observe the use term of a solvent and use the storage container of a solvent to be clean.

Be cautious of fire enough.

Way of Cleaning

First, the surface of window glass is wiped with the wiping cloth into which the cleaner was infiltrated. Please wipe down the surface of window glass at least 2 times or more.

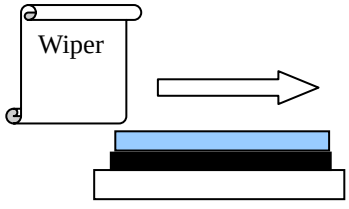
Next, the surface of window glass wipes with the dry wiping cloth. Please wipe down the surface of window glass at least 3 times or more.

Finally, blow cleaning is performed by dry N2 filtered.

If operator wipes the surface of the window glass with the above-mentioned process and dirt still remains, Toshiba recommends repeating the clean operation from the beginning.

Be cautious of the next thing.

a. Don't infiltrate the cleaner too much.
b. A wiping portion is performed into the optical range and don't touch the edge of window glass.
c. Be sure to wipe in a long direction and the same direction.
d. A wiping cloth always uses an unused portion.



10. Foot Pattern on the PCB

We recommend fig1 's foot pattern for your PCB(Printed circuit Board).

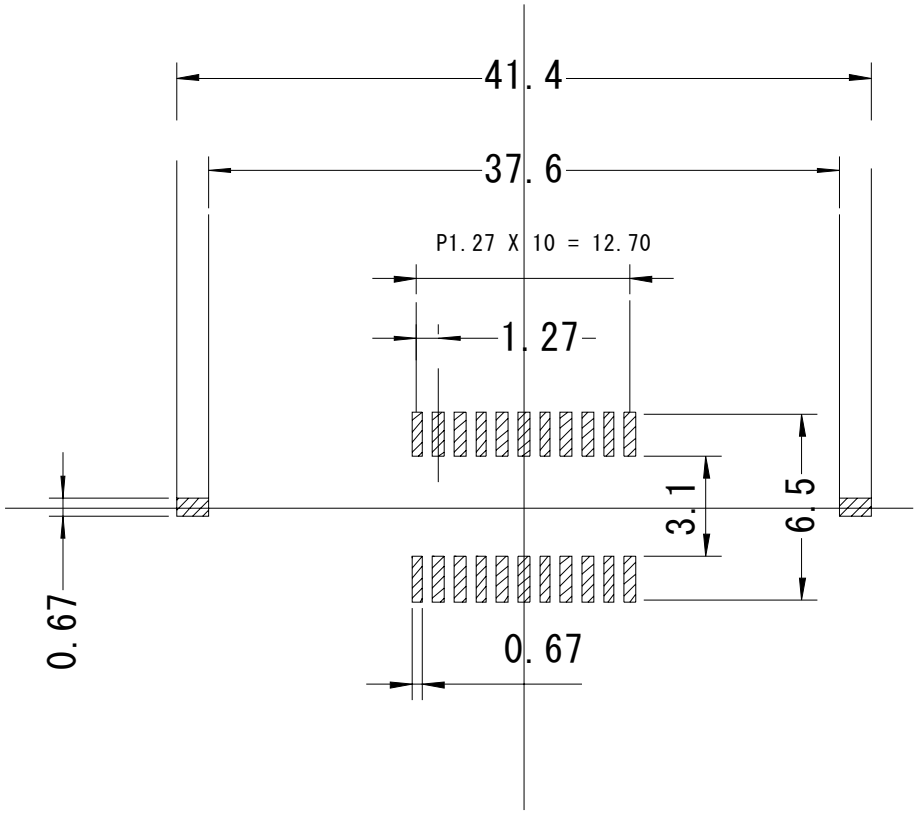


fig1

11. Mask for Solder Paste Application

We recommend metal mask that have the following thickness.

・TCD****BFG(Pad material : Au) : a thickness of 0.2mm.

And we recommend that the size of the pattern of the metal mask is 95% to 100% of recommended foot pattern at fig1.

12. Temperature cycle

After mounting, if temperature cycle stress is too much, CCD surface mount products have a possibility that a crack may arise in solder. As a method of preventing a solder crack, underfil is effective

13. Reuse of a Tray

We reuse tray in order to reduce plastic waste as we can. Please cooperate with us in reusing for ecology.

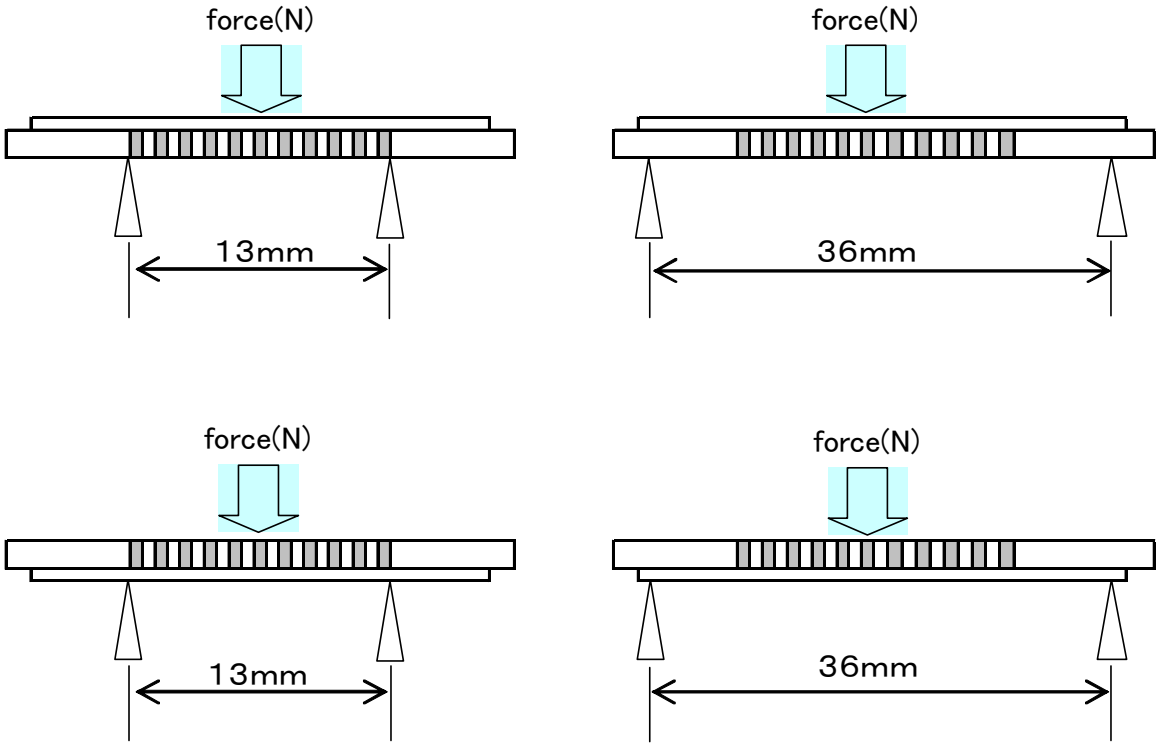
14. Caution for Package Handling

Over force on CCD products may cause crack and chip removing on the product. The three point bending strength of this product is the following. (Reference data)

If the stress is loaded far from a fulcrum, the stress on the package will be increase.

When you will treat CCD on every process, please be careful particularly. For example, soldering on PCB, cutting PCB, wiping on the glass surface, optical assemble and so on.

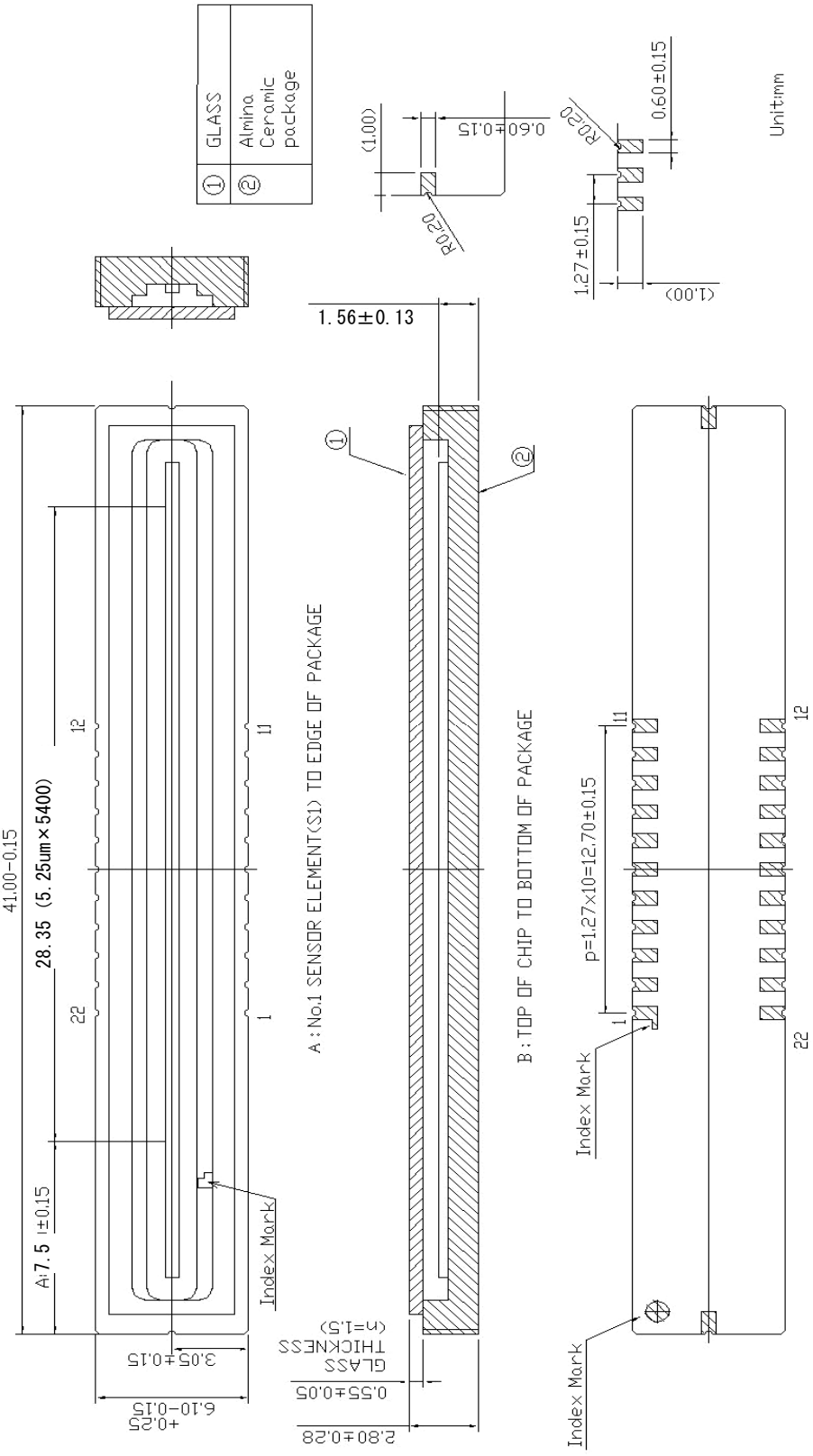
Bending Test



・22CLCC

Bearing length 13mm :	The force from upside : 300[N]
	The force from downside : 200[N]
Bearing length 36mm :	The force from upside : 150[N]
	The force from downside : 80[N]

Package Dimensions



Weight: 2.0 g (typ.)

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060925EBA_R6

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